NSN 5961-01-024-0580

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View Online at https://aerobasegroup.com/nsn/5961-01-024-0580 **Inclosure Material:** Metal **Overall Length:** 0.210 inches **Terminal Length:** 0.500 inches **Overall Height:** Between 0.190 inches and 0.200 inches **Overall Diameter:** Between 0.187 inches and 0.210 inches **Internal Configuration:** Field effect **Electrode Internally-electrically Connected To Case:** Base **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 25.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 50.00 milliamperes collector current, dc **Power Rating Per Characteristic:** 600.0 milliwatts total device dissipation **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 uninsulated wire lead **Reference Number Differentiating Characteristics:** Selected item as per iec dwg no. P00347203 Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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